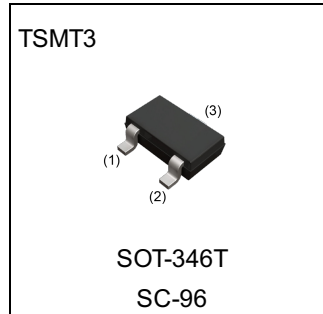


Parameter	Value
V_{CEO}	-30V
I_C	-1A

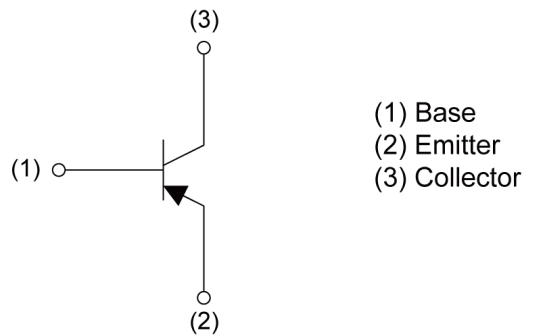
●Outline



●Features

- 1)A collector current is large.
- 2)Collector saturation voltage is low.
 $V_{CE(sat)} \leq -350mV$
 at $I_C = -500mA / I_B = -25mA$

●Inner circuit



●Application

LOW FREQUENCY AMPLIFIER

●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SB1710	TSMT3	2928	TL	180	8	3000	EW

● **Absolute maximum ratings** ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	-30	V
Collector-emitter voltage	V_{CEO}	-30	V
Emitter-base voltage	V_{EBO}	-6	V
Collector current	I_C	-1	A
	I_{CP}^{*1}	-2	A
Power dissipation	P_D^{*2}	0.5	W
	P_D^{*3}	1.0	W
Junction temperature	T_j	150	$^\circ\text{C}$
Range of storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

● **Electrical characteristics** ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV_{CBO}	$I_C = -10\mu\text{A}$	-30	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = -1\text{mA}$	-30	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_E = -10\mu\text{A}$	-6	-	-	V
Collector cut-off current	I_{CBO}	$V_{CB} = -30\text{V}$	-	-	-100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = -6\text{V}$	-	-	-100	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -500\text{mA}, I_B = -25\text{mA}$	-	-150	-350	mV
DC current gain	h_{FE}	$V_{CE} = -2\text{V}, I_C = -100\text{mA}$	270	-	680	-
Transition frequency	f_T	$V_{CE} = -2\text{V}, I_E = 100\text{mA}, f = 100\text{MHz}$	-	320	-	MHz
Output capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$	-	7	-	pF

*1 $P_w=1\text{ms}$ Single pulse

*2 Each Terminal Mounted on a Reference Land.

*3 Mounted on a ceramic board.($25\times 25\times 0.8\text{mm}$)

● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.1 Ground Emitter Propagation Characteristics

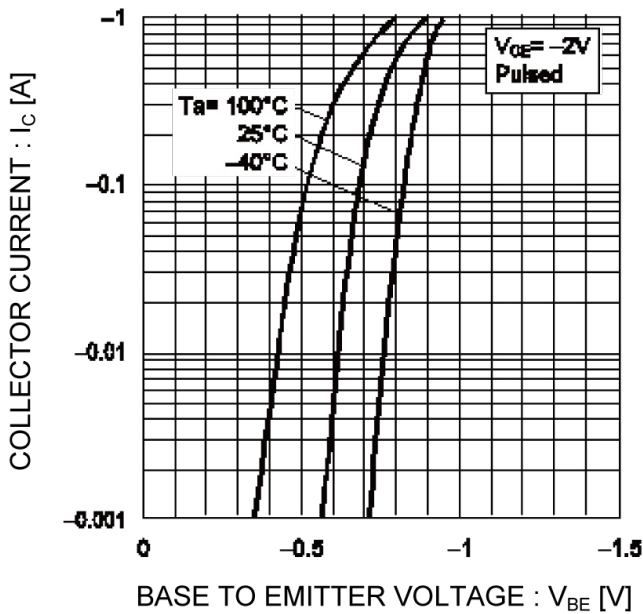


Fig.2 Typical Output Characteristics

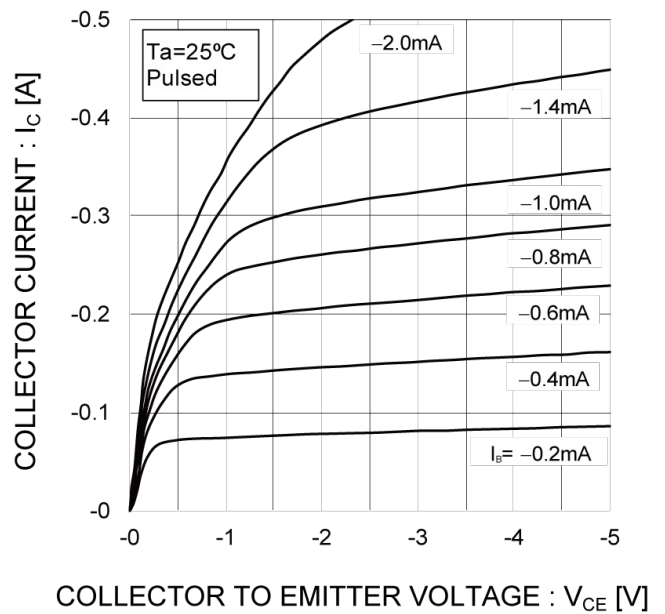


Fig.3 DC Current Gain vs. Collector Current (I)

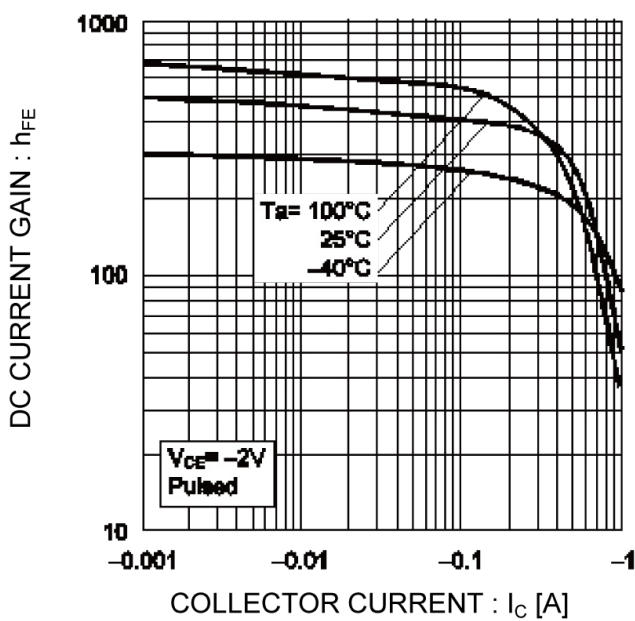
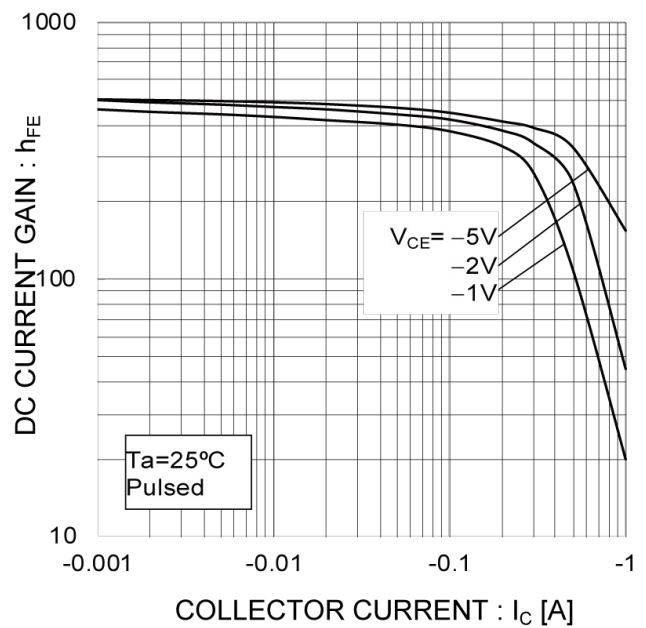


Fig.4 DC Current Gain vs. Collector Current (II)



● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

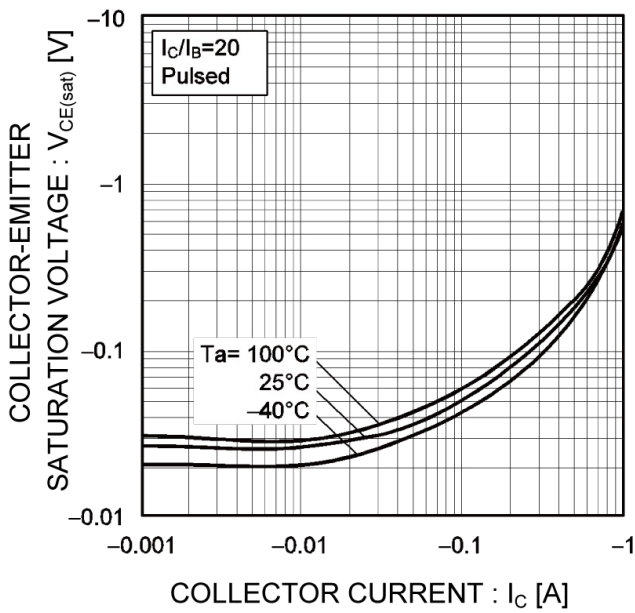


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

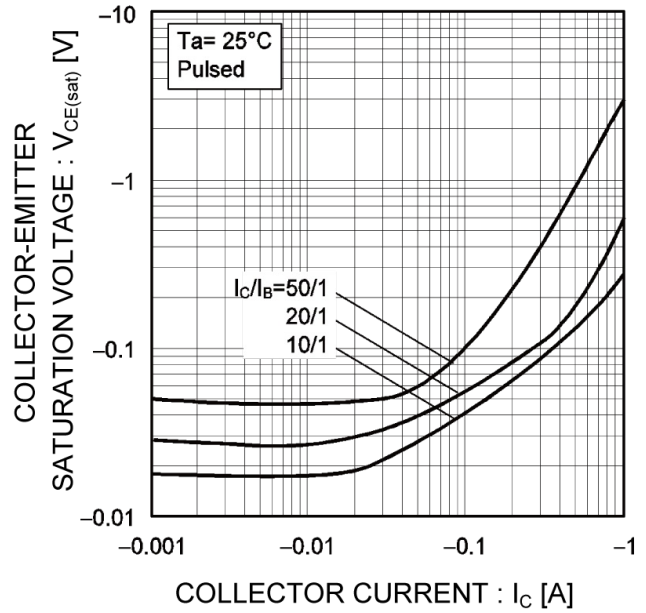


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

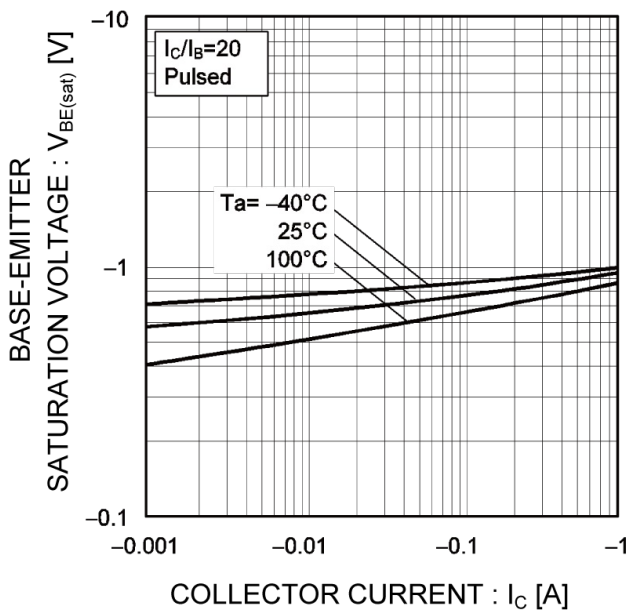
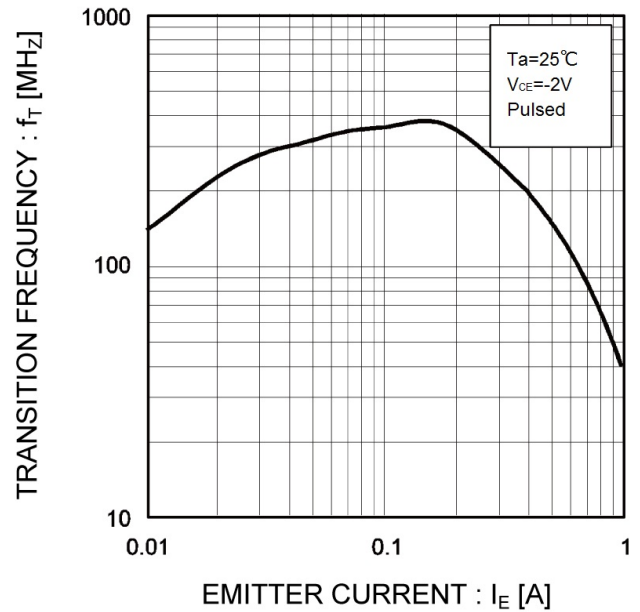


Fig.8 Gain Bandwidth Product vs. Emitter Current



● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.9 Emitter Input Capacitance vs. Emitter-Base Voltage
Collector Output Capacitance vs. Collector-Base Voltage

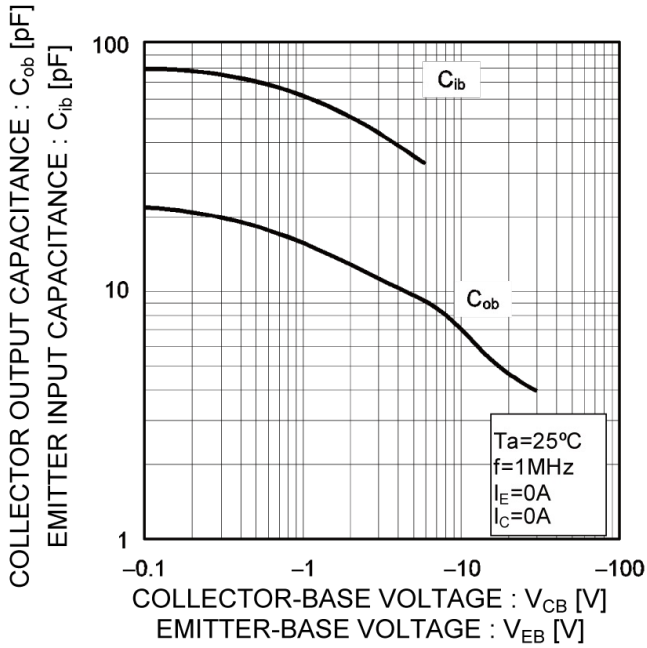
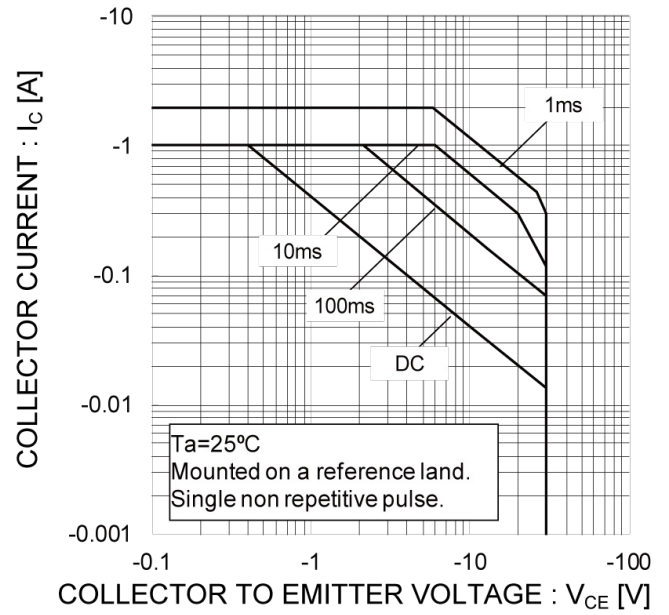


Fig.10 Safe Operating Area



●Dimensions

TSMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	-	1.00	-	0.039
A1	0.00	0.10	0.000	0.004
A2	0.75	0.95	0.030	0.037
A3	0.25		0.010	
b	0.35	0.50	0.014	0.020
c	0.10	0.26	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.05	0.25	0.002	0.010
x	-	0.20	-	0.008

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.70	-	0.028
e1	2.10		0.083	
l1	-	0.90	-	0.035

Dimension in mm/inches

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